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October 2013

# ISL9V3036D3S / ISL9V3036S3S / ISL9V3036P3

# EcoSPARK® 300mJ, 360V, N-Channel Ignition IGBT

# **General Description**

The ISL9V3036D3S, ISL9V3036S3S, and ISL9V3036P3 are the next generation IGBTs that offer outstanding SCIS capability in the space saving D-Pak (TO-252), as well as the industry standard D²-Pak (TO-263) and TO-220 plastic packages. These devices are intended for use in automotive ignition circuits, specifically as a coil drivers. Internal diodes provide voltage clamping without the need for external components.

**EcoSPARK®** devices can be custom made to specific clamp voltages. Contact your nearest Fairchild sales office for more information.

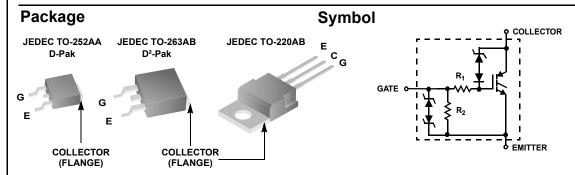
Formerly Developmental Type 49442

# **Applications**

- · Automotive Ignition Coil Driver Circuits
- · Coil- On Plug Applications

# **Features**

- Industry Standard D<sup>2</sup>-Pak package
- SCIS Energy = 300mJ at T<sub>J</sub> = 25°C
- · Logic Level Gate Drive



# Device Maximum Ratings T<sub>.i</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
BV <sub>CER</sub>	Collector to Emitter Breakdown Voltage (I <sub>C</sub> = 1 mA)	360	V
BV <sub>ECS</sub>	Emitter to Collector Voltage - Reverse Battery Condition (I <sub>C</sub> = 10 mA)	24	V
E <sub>SCIS25</sub>	$T_J = 25$ °C, $I_{SCIS} = 14.2A$ , L = 3.0 mHy	300	mJ
E <sub>SCIS150</sub>	$T_J = 150$ °C, $I_{SCIS} = 10.6A$ , L = 3.0 mHy	170	mJ
I <sub>C25</sub>	Collector Current Continuous, At T <sub>C</sub> = 25°C, See Fig 9	21	Α
I <sub>C110</sub>	Collector Current Continuous, At T <sub>C</sub> = 110°C, See Fig 9	17	Α
$V_{GEM}$	Gate to Emitter Voltage Continuous	±10	V
P <sub>D</sub>	Power Dissipation Total T <sub>C</sub> = 25°C	150	W
	Power Dissipation Derating T <sub>C</sub> > 25°C	1.0	W/°C
T <sub>J</sub>	Operating Junction Temperature Range	-40 to 175	°C
T <sub>STG</sub>	Storage Junction Temperature Range	-40 to 175	°C
TL	Max Lead Temp for Soldering (Leads at 1.6mm from Case for 10s)	300	°C
T <sub>pkg</sub>	Max Lead Temp for Soldering (Package Body for 10s)	260	°C
ESD	Electrostatic Discharge Voltage at 100pF, 1500 $\Omega$	4	kV

evice Mar	king	Device	Package	Reel Size	<b>)</b>	Tape	Width		Quantity	
V3036D		ISL9V3036D3ST	TO-252AA	330mm		16mm			2500	
V3036S ISL9V3036S3ST TO-26		TO-263AB	330mm		24mm			800		
V3036P		ISL9V3036P3	TO-220AA	Tube		N/A			50	
V3036D		ISL9V3036D3S	TO-252AA	Tube		N/A			75	
V3036S		ISL9V3036S3S	TO-263AB	Tube		1	N/A		50	
	al C	haracteristic		_		N#1	<b>-</b>		11-14-	
Symbol		Paramet	er	Test Con	aitions	Min	Тур	Max	Units	
		acteristics		_						
BV <sub>CER</sub>	Colle	ector to Emitter Brea	$I_C$ = 2mA, $V_{GE}$ $R_G$ = 1K $\Omega$ , See $T_J$ = -40 to 150	330	360	390	V			
BV <sub>CES</sub>	Colle	ector to Emitter Brea	$I_C = 10 \text{mA}, V_{GE} = 0,$ $R_G = 0, \text{ See Fig. 15}$ $T_A = -40 \text{ to } 150^{\circ}\text{C}$		350	380	410	V		
BV <sub>ECS</sub>	Emit	Emitter to Collector Breakdown Voltage		$I_C = -75 \text{mA}, V_{GE} = 0 \text{V},$ $T_C = 25 ^{\circ}\text{C}$		30	-	-	V	
BV <sub>GES</sub>	Gate	e to Emitter Breakdo	wn Voltage	$I_{GES} = \pm 2mA$		±12	±14	-	V	
I <sub>CER</sub>	Colle	ector to Emitter Lea	kage Current	V <sub>CER</sub> = 250V,	T <sub>C</sub> = 25°C	-	-	25	μA	
				$R_G$ = 1KΩ, See Fig. 11	T <sub>C</sub> = 150°C	-	-	1	mA	
I <sub>ECS</sub>	Emit	ter to Collector Leal	V <sub>EC</sub> = 24V, See		-	-	1	mA		
			Fig. 11	T <sub>C</sub> = 150°C	-	-	40	mA		
R <sub>1</sub>	-	es Gate Resistance				-	70	-	Ω	
R <sub>2</sub>	Gate	e to Emitter Resistar	nce			10K	-	26K	Ω	
n State (	Char	acteristics								
V <sub>CE(SAT)</sub>	Colle	ollector to Emitter Saturation Voltage		$I_C = 6A$ , $V_{GE} = 4V$	T <sub>C</sub> = 25°C, See Fig. 3	-	1.25	1.60	V	
V <sub>CE(SAT)</sub>	Colle	ollector to Emitter Saturation Voltage		$I_C = 10A,$ $V_{GE} = 4.5V$	T <sub>C</sub> = 150°C, See Fig. 4	-	1.58	1.80	V	
$V_{CE(SAT)}$	Colle	collector to Emitter Saturation Voltage		$I_C = 15A,$ $V_{GE} = 4.5V$	T <sub>C</sub> = 150°C	-	1.90	2.20	V	
ynamic	Char	acteristics								
Q <sub>G(ON)</sub>	Gate	e Charge		I <sub>C</sub> = 10A, V <sub>CE</sub> = 12V, V <sub>GE</sub> = 5V, See Fig. 14		-	17	-	nC	
$V_{GE(TH)}$	Gate	e to Emitter Thresho	ld Voltage	I <sub>C</sub> = 1.0mA,	T <sub>C</sub> = 25°C	1.3	-	2.2	V	
			V <sub>CE</sub> = V <sub>GE,</sub> See Fig. 10	T <sub>C</sub> = 150°C	0.75	-	1.8	V		
$V_{GEP}$	Gate	e to Emitter Plateau	Voltage	I <sub>C</sub> = 10A,	V <sub>CE</sub> = 12V	-	3.0	-	V	
witching	Cha	aracteristics								
t <sub>d(ON)R</sub>	Curi	Current Turn-On Delay Time-Resistive		$V_{CE} = 14V, R_{L} = 1\Omega,$		-	0.7	4	μs	
t <sub>rR</sub>		Current Rise Time-Resistive		$V_{GE}$ = 5V, $R_G$ = 1K $\Omega$ T <sub>J</sub> = 25°C, See Fig. 12		-	2.1	7	μs	
t <sub>d(OFF)L</sub>	_	Current Turn-Off Delay Time-Inductive		$V_{CE} = 300V, R_{L} = 500\mu H,$		-	4.8	15	μs	
t <sub>fL</sub>		ent Fall Time-Induc		$V_{GE}$ = 5V, $R_G$ = 1K $\Omega$ $T_J$ = 25°C, See Fig. 12		-	2.8	15	μs	
SCIS	Self	Clamped Inductive	$T_J = 25^{\circ}C, L = 3.0 \text{ mH},$ $R_G = 1K\Omega, V_{GE} = 5V$		-	-	300	mJ		
-										
hermal C	har	acteristics								

# **Typical Performance Curves**

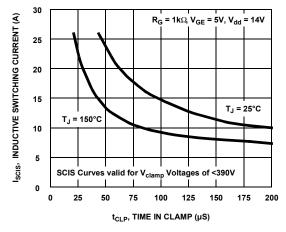


Figure 1. Self Clamped Inductive Switching Current vs Time in Clamp

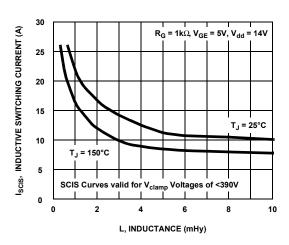


Figure 2. Self Clamped Inductive Switching Current vs Inductance

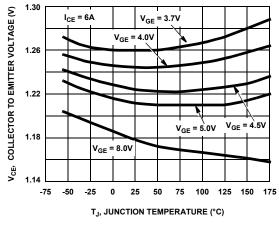


Figure 3. Collector to Emitter On-State Voltage vs Junction Temperature

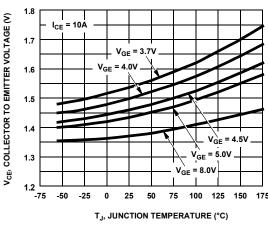


Figure 4. Collector to Emitter On-State Voltage vs Junction Temperature

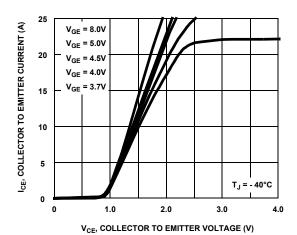


Figure 5. Collector to Emitter On-State Voltage vs Collector Current

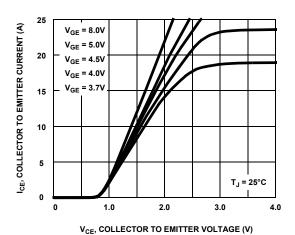


Figure 6. Collector to Emitter On-State Voltage vs Collector Current

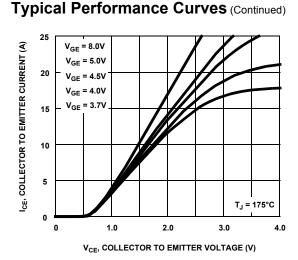


Figure 7. Collector to Emitter On-State Voltage vs Collector Current

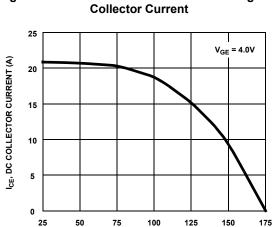


Figure 9. DC Collector Current vs Case Temperature

T<sub>C</sub>, CASE TEMPERATURE (°C)

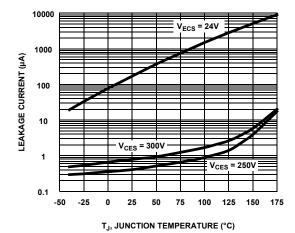


Figure 11. Leakage Current vs Junction Temperature

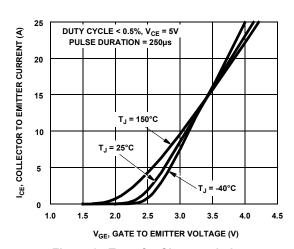


Figure 8. Transfer Characteristics

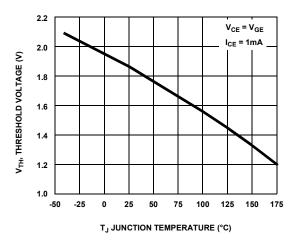


Figure 10. Threshold Voltage vs Junction Temperature

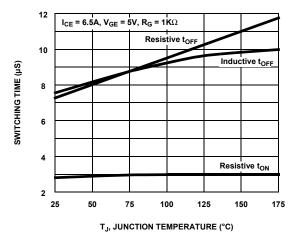


Figure 12. Switching Time vs Junction Temperature

# Typical Performance Curves (Continued) FREQUENCY = 1 MHz Column 1200 Column 1200

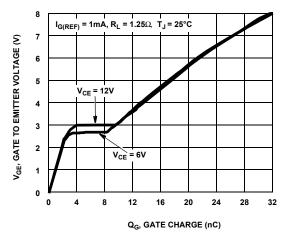


Figure 13. Capacitance vs Collector to Emitter Voltage

V<sub>CE</sub>, COLLECTOR TO EMITTER VOLTAGE (V)

Figure 14. Gate Charge

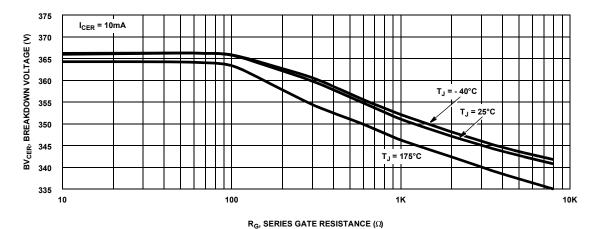


Figure 15. Breakdown Voltage vs Series Gate Resistance

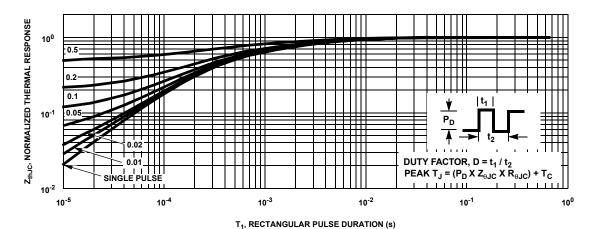
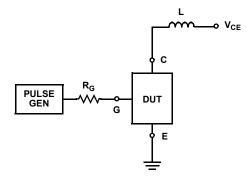


Figure 16. IGBT Normalized Transient Thermal Impedance, Junction to Case

# **Test Circuit and Waveforms**



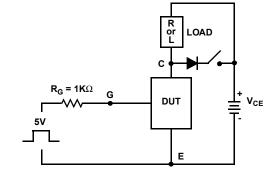
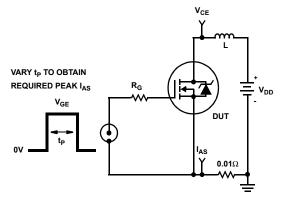
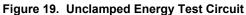


Figure 17. Inductive Switching Test Circuit

Figure 18.  $t_{\rm ON}$  and  $t_{\rm OFF}$  Switching Test Circuit





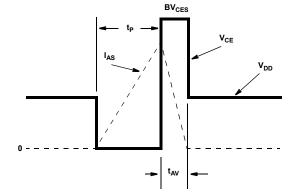


Figure 20. Unclamped Energy Waveforms

# SPICE Thermal Model JUNCTION **REV 24 April 2002** ISL9V3036D3S/ ISL9V3036S3S / ISL9V3036P3 CTHERM1 th 6 2.1e -3 CTHERM2 6 5 1.4e -1 RTHERM1 CTHERM1 CTHERM3 5 4 7.3e -3 CTHERM4 4 3 2.1e -1 CTHERM5 3 2 1.1e -1 CTHERM6 2 tl 6.2e +6 6 RTHERM1 th 6 1.2e -1 RTHERM2 6 5 1.9e -1 RTHERM2 CTHERM2 RTHERM3 5 4 2.2e -1 RTHERM4 4 3 6.0e -2 RTHERM5 3 2 5.8e -2 RTHERM6 2 tl 1.6e -3 5 SABER Thermal Model RTHERM3 CTHERM3 SABER thermal model ISL9V3036D3S / ISL9V3036S3S / ISL9V3036P3 template thermal\_model th tl thermal\_c th, tl ctherm.ctherm1 th 6 = 2.1e - 3ctherm.ctherm2 6 5 = 1.4e -1 ctherm.ctherm3 5 4 = 7.3e -3 RTHERM4 CTHERM4 ctherm.ctherm4 4 3 = 2.2e -1 ctherm.ctherm5 3 2 =1.1e -1 ctherm.ctherm6 2 tl = 6.2e +6 3 rtherm.rtherm1 th 6 = 1.2e -1 rtherm.rtherm2 6 5 = 1.9e -1 rtherm.rtherm3 5 4 = 2.2e -1 RTHERM5 CTHERM5 rtherm.rtherm4 4 3 = 6.0e -2 rtherm.rtherm5 3 2 = 5.8e -2 rtherm.rtherm6 2 tl = 1.6e -3 2 RTHERM6 CTHERM6 CASE





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Definition of Terms					
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
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